

# **Maximum Ratings** $(@T_A = +25^{\circ}C, \text{ unless otherwise specified.})$

Characteristic			Symbol	Value	Units
Drain-Source Voltage			$V_{DSS}$	100	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	3.8 3.0	Α
	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	5.3 4.2	Α
Continuous Dunin Comment (Note C) // C)/	Steady State	$T_A = +25$ °C $T_A = +70$ °C	I <sub>D</sub>	3.6 2.9	Α
Continuous Drain Current (Note 6) V <sub>GS</sub> = 6V	t<10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	5.0 4.0	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			$I_{DM}$	20	А

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Dower Dissination (Note 5)	$T_A = +25^{\circ}C$	Б	1.0	W
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	P <sub>D</sub>	0.6	
Thermal Decistores, Junction to Ambient (Note 5)	Steady state		131	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	76	
Total Bower Dissipation (Note 6)	$T_A = +25^{\circ}C$	D	2.4	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	$P_{D}$	1.5	
Thermal Decistores, Junction to Ambient (Note 6)	Steady state	Б.	52	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	27	
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	6.9	
Operating and Storage Temperature Range		$T_{J_i} T_{STG}$	-55 to +150	°C

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						•	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	-	-	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	1.0	μΑ	V <sub>DS</sub> = 80V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)						•	
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.5	2.0	3.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Otatia Pasia Ocupa Oc. Pasiatana	Б	-	68	110	mΩ	$V_{GS} = 10V, I_D = 3.3A$	
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>	-	75	122		$V_{GS} = 6.0V, I_D = 3.0A$	
Forward Transfer Admittance	Y <sub>fs</sub>	-	13	-	S	$V_{DS} = 10V, I_{D} = 3.3A$	
Diode Forward Voltage	V <sub>SD</sub>	-	0.78	-	V	$V_{GS} = 0V, I_S = 3.2A$	
DYNAMIC CHARACTERISTICS (Note 8)						·	
Input Capacitance	C <sub>iss</sub>	-	549	-	pF	$V_{DS} = 50V, V_{GS} = 0V,$ f = 1.0MHz	
Output Capacitance	Coss	-	41.1	-	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	-	19.0	-	pF		
Gate Resistance	Rg	-	1.6	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge V <sub>GS</sub> = 10V	Qg	-	10.6	-	nC	V <sub>DS</sub> = 50V, I <sub>D</sub> = 3.3A	
Total Gate Charge V <sub>GS</sub> = 4.5V	Qq	-	5.2	-	nC		
Gate-Source Charge	Q <sub>gs</sub>	-	2.3	-	nC		
Gate-Drain Charge	Q <sub>qd</sub>	-	2.6	-	nC		
Turn-On Delay Time	t <sub>D(on)</sub>	-	3.8	-	ns	$V_{GS} = 10V, V_{DS} = 50V,$ $R_G = 6.0\Omega, I_D = 3.3A$	
Turn-On Rise Time	tr	-	1.8	-	ns		
Turn-Off Delay Time	t <sub>D(off)</sub>	-	11.5	-	ns		
Turn-Off Fall Time	tf	-	2.5	-	ns		

Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.

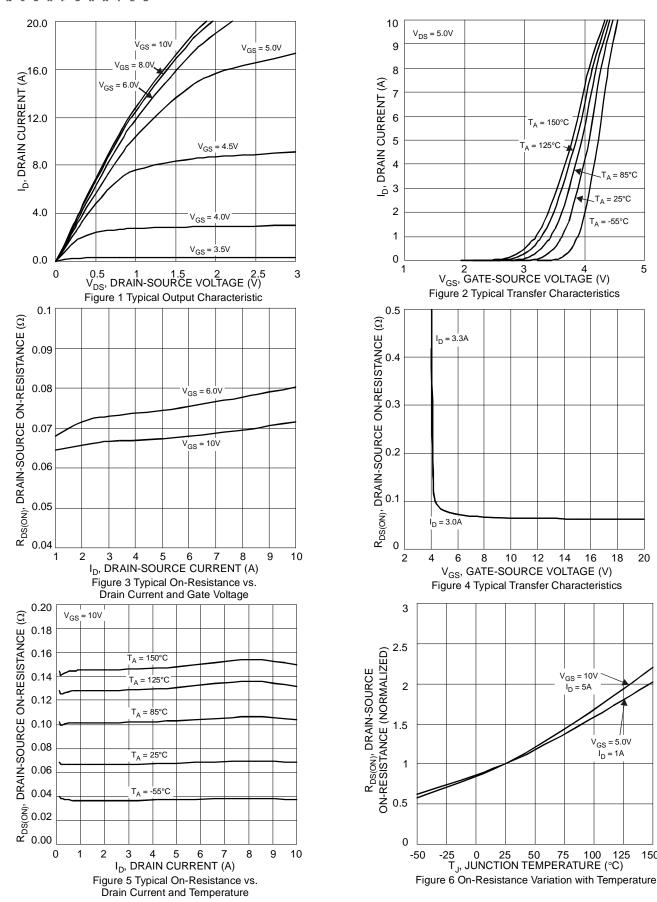
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## DMN10H120SFG

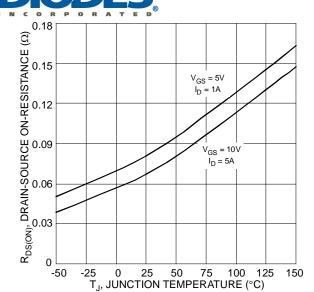
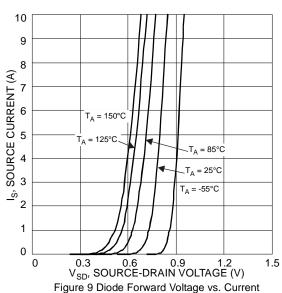
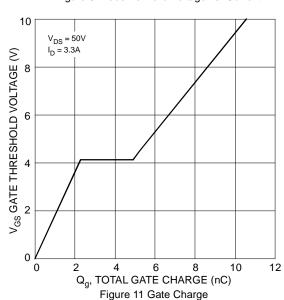


Figure 7 On-Resistance Variation with Temperature





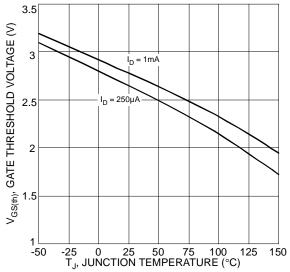
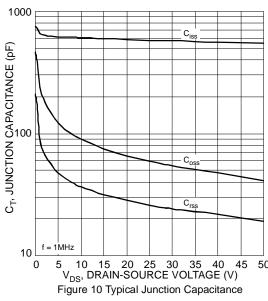


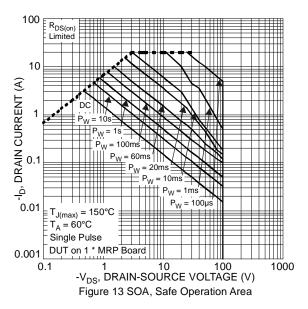
Figure 8 Gate Threshold Variation vs. Ambient Temperature

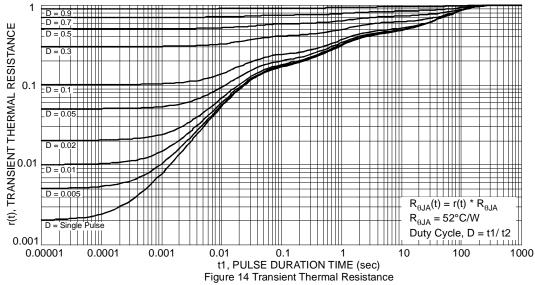


100⊨ R<sub>DS(on)</sub> Limited 10 -I<sub>D</sub>, DRAIN CURRENT (A) 0.01 T<sub>J(max)</sub> = 150°C T<sub>A</sub> = 25°C Single Pulse DUT on 1 \* MRP Board 0.001 10 1000 -V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V) Figure 12 SOA, Safe Operation Area

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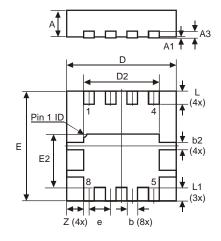






## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

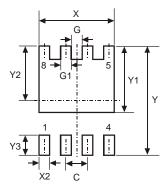


POWERDI3333-8					
Dim	Min	Max	Тур		
D	3.25	3.35	3.30		
Е	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E2	1.56	1.66	1.61		
Α	0.75	0.85	0.80		
A1	0	0.05	0.02		
А3	_	_	0.203		
b	0.27	0.37	0.32		
b2	-	-	0.20		
L	0.35	0.45	0.40		
L1	_	_	0.39		
е	_	_	0.65		
Ζ	_	_	0.515		
All Dimensions in mm					



### Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.650
G	0.230
G1	0.420
Υ	3.700
Y1	2.250
Y2	1.850
Y3	0.700
Х	2.370
X2	0.420

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